Technical Data Data Sheet 3384, Rev. A

### MBRF30200CT SCHOTTKY RECTIFIER

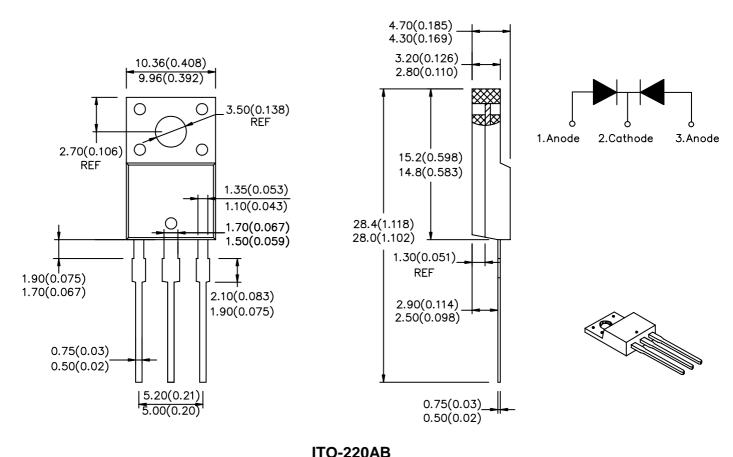
#### **Applications:**

• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

#### **Features:**

- 150 ℃ T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

#### Mechanical Dimensions: In Inches / mm



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## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	200	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =133°C, rectangular wave form	30	Α
Peak Repetitive Forward Current (per leg)	I <sub>FRM</sub>	Rated V <sub>R</sub> square wave 20KHz T <sub>C</sub> =133°C	20	Α
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	150	А

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	vard Voltage Drop $V_{F1}$ @ 15A, Pulse, $T_J = 25$ °C		0.90	V
(per leg)*		@ 30A, Pulse, T <sub>J</sub> = 25 °C	1.05	
	$V_{F2}$	@ 15 A, Pulse, T <sub>J</sub> = 125 °C	0.70	V
		@ 30 A, Pulse, T <sub>J</sub> = 125 °C	0.85	
Max. Reverse Current (per $I_{R1}$ @ $V_R$ = rated $V_R$		$@V_R = rated V_R$	1.0	mA
leg)*		T <sub>J</sub> = 25 °C		
	$I_{R2}$	$@V_R = rated V_R$	6.0	mA
		T <sub>J</sub> = 125 °C		
Max. Junction Capacitance	C <sub>T</sub>	$@V_R = 5V, T_C = 25  ^{\circ}C$	400	pF
(per leg)		$f_{SIG} = 1MHz$		
Typical Series Inductance	L <sub>S</sub>	Measured lead to lead 5 mm from	8.0	nΗ
(per leg)		package body		
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs
RSM Isolation Voltage	$V_{ISO}$	Clip mounting, the epoxy body	4500	V
(t = 1.0 second, R. H. < =30%,		away from the heatsink edge by		
$T_A = 25  ^{\circ}C$		more than 0.110" along the lead		
		direction.		
		Clip mounting, the epoxy body is	3500	
		inside the heatsink.		-
		Screw mounting, the epoxy body is inside the heatsink.	1500	
	ĺ	is inside the neatsink.		1

<sup>\*</sup> Pulse Width < 300µs, Duty Cycle <2%

# Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units	
Max. Junction Temperature	$T_J$	-	-55 to +150	Ô	
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C	
Maximum Thermal Resistance Junction to Case (per leg)	$R_{\theta JC}$	DC operation	3.5	°C/W	
Approximate Weight	wt	-	2	g	
Mounting Torque	T <sub>M</sub>	-	6(Min.) 12(Max.)	Kg-cm	
Case Style	ITO-220AB				

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